CMOS Digital Integrated Circuits Silicon Monolithic

74HC373D

1. Functional Description

- Octal D-Type Latch with 3-State Outputs

2. General

The 74HC373D is a high speed CMOS OCTAL LATCH with 3-STATE OUTPUT fabricated with silicon gate C2MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

These 8-bit D-type latches are controlled by a latch enable input (LE) and an output enable input (OE).

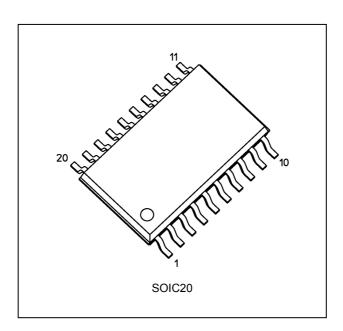
When the \overline{OE} input is high, the eight outputs are in a high impedance state.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

3. Features

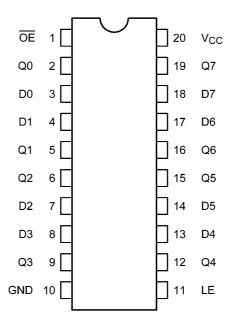
- (1) High speed: $t_{pd} = 12 \text{ ns (typ.)}$ at $V_{CC} = 6.0 \text{ V}$
- (2) Low power dissipation: $I_{CC} = 4.0 \mu A \text{ (max)}$ at $T_a = 25 \text{ °C}$
- (3) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (4) Wide operating voltage range: $V_{CC(opr)} = 2.0 \text{ V}$ to 6.0 V

4. Packaging

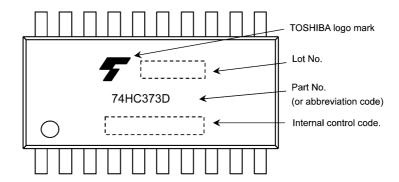




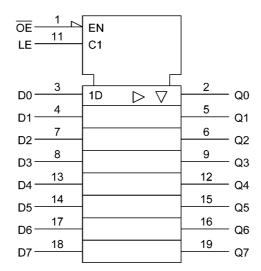
5. Pin Assignment



6. Marking



7. IEC Logic Symbol



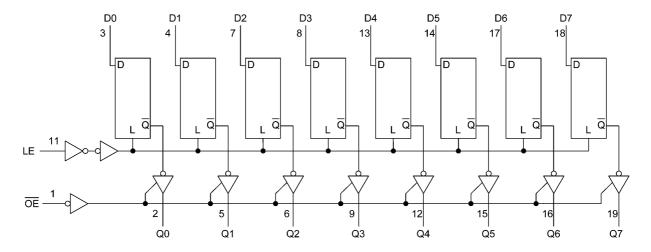
8. Truth Table

INPUT OE	INPUT LE	INPUT D	OUTPUT Q
Н	Х	Х	Z
L	L	Х	Qn
L	Н	L	L
L	Н	Н	Н

X: Don't CareZ: High Impedance

Qn: Q outputs are latched at the time when the LE input is taken to low logic level.

9. System Diagram





10. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to V _{CC} + 0.5	V
Output voltage	V _{OUT}		-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}		±20	mA
Output diode current	I _{OK}		±20	mA
Output current	I _{OUT}		±35	mA
V _{CC} /ground current	I _{CC}		±75	mA
Power dissipation	P_{D}	(Note 1)	500	mW
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: PD derates linearly with -8 mW/°C above 85°C

11. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V _{CC}	_	2.0 to 6.0	V
Input voltage	V _{IN}		0 to 5.5	V
Output voltage	V _{OUT}		0 to V _{CC}	V
Operating temperature	T _{opr}		-40 to 125	°C
Input rise and fall times	t _r ,t _f	_	0 to 50	μS

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.



12. Electrical Characteristics

12.1. DC Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition	1	V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.50	_	_	V
				4.5	3.15	_	_	V
				6.0	4.20	_	_	V
Low-level input voltage	V _{IL}	_		2.0			0.50	V
				4.5			1.35	V
				6.0			1.80	V
High-level output voltage	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	I_{OH} = -20 μ A	2.0	1.9	2.0	_	V
				4.5	4.4	4.5	_	
				6.0	5.9	6.0	_	
			I_{OH} = -6 mA	4.5	4.18	4.31	_	
			I_{OH} = -7.8 mA	6.0	5.68	5.80	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 20 μA	2.0		0.0	0.1	V
				4.5	_	0.0	0.1	
				6.0	_	0.0	0.1	
			I _{OL} = 6 mA	4.5	_	0.17	0.26	
			I _{OL} = 7.8 mA	6.0	_	0.18	0.26	V
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		6.0	I	ı	±0.5	μА
Input leakage current	I _{IN}	$V_{IN} = V_{CC}$ or GND	_	6.0	_	_	±0.1	μА
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND I _O = 0 A		6.0	_	_	4.0	μА

12.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Condition	1	V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.50	_	V
				4.5	3.15	_	
				6.0	4.20	_	V
Low-level input voltage	V _{IL}	_		2.0		0.50	V
				4.5		1.35	
				6.0	_	1.80	V
High-level output voltage	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OH} = -20 μA	2.0	1.9	_	V
				4.5	4.4	_	
				6.0	5.9	_	
			I _{OH} = -6 mA	4.5	4.13	_	
			$I_{OH} = -7.8 \text{ mA}$	6.0	5.63	_	
Low-level output voltage	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 20 μA	2.0		0.1	V
				4.5		0.1	
				6.0	_	0.1	
			$I_{OL} = 6 \text{ mA}$	4.5		0.33	
			I _{OL} = 7.8 mA	6.0	_	0.33	V
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		6.0	l	±5.0	μА
Input leakage current	I _{IN}	$V_{IN} = V_{CC}$ or GND		6.0	_	±1.0	μА
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND $I_O = 0$ A		6.0	_	40.0	μА



12.3. DC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Condition	1	V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.50	_	V
				4.5	3.15	_	
				6.0	4.20	_	V
Low-level input voltage	V _{IL}	_		2.0	_	0.50	V
				4.5		1.35	
				6.0	_	1.80	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -20 μA	2.0	1.9	_	V
				4.5	4.4	_	
				6.0	5.9	_	
			I _{OH} = -6 mA	4.5	3.7	_	
			I _{OH} = -7.8 mA	6.0	5.2	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 20 μA	2.0	_	0.1	V
				4.5	_	0.1	
				6.0	_	0.1	
			I _{OL} = 6 mA	4.5	_	0.4	
			I _{OL} = 7.8 mA	6.0	_	0.4	V
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		6.0	_	±10.0	μА
Input leakage current	I _{IN}	$V_{IN} = V_{CC}$ or GND		6.0	_	±1.0	μА
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND $I_{O} = 0$ A		6.0	_	160.0	μА



12.4. Timing Requirements (Unless otherwise specified, $T_a = 25$ °C, Input: $t_f = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Limit	Unit
Minimum pulse width (LE)	t _{w(H)}	_	2.0	75	ns
			4.5	15	
			6.0	13	
Minimum setup time (Dn)	ts	_	2.0	50	ns
			4.5	10	
			6.0	9	
Minimum hold time (Dn)	t _h	_	2.0	5	ns
			4.5	5	
			6.0	5	

12.5. Timing Requirements (Unless otherwise specified, T_a = -40 to 85 °C, Input: t_r = t_f = 6 ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Limit	Unit
Minimum pulse width (LE)	t _{w(H)}	_	2.0	95	ns
			4.5	19	
			6.0	16	
Minimum setup time (Dn)	t _S	_	2.0	65	ns
			4.5	13	
			6.0	11	
Minimum hold time (Dn)	t _h	_	2.0	5	ns
			4.5	5	
			6.0	5	

12.6. Timing Requirements (Unless otherwise specified, T_a = -40 to 125 °C, Input: t_r = t_f = 6 ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Limit	Unit
Minimum pulse width (LE)	t _{w(H)}	_	2.0	120	ns
			4.5	24	
			6.0	20	
Minimum setup time (Dn)	t _S	_	2.0	75	ns
			4.5	15	
			6.0	13	
Minimum hold time (Dn)	t _h	_	2.0	5	ns
			4.5	5	
			6.0	5	



12.7. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Output transition time	t _{TLH} ,t _{THL}		_	2.0	50	_	20	60	ns
				4.5]	_	6	12	
				6.0] [_	5	10	
Propagation delay time	t _{PLH} ,t _{PHL}		_	2.0	50	_	42	125	ns
(LE-Q)				4.5]	_	14	25	
				6.0] [_	12	21	
				2.0	150	_	57	175	ns
				4.5]	_	19	35	
				6.0] [_	16	30	
Propagation delay time	t _{PLH} ,t _{PHL}		_	2.0	50	_	42	125	ns
(D-Q)				4.5]	_	14	25	
				6.0] [_	12	21	
				2.0	150	_	57	175	ns
				4.5]	_	19	35	
				6.0] [_	16	30	
Output enable time	t_{PZL},t_{PZH}		$R_L = 1 k\Omega$	2.0	50	_	39	125	ns
				4.5] [_	13	25	
				6.0		_	11	21	
				2.0	150	_	54	175	ns
				4.5		_	18	35	
				6.0		_	15	30	
Output disable time	t_{PLZ}, t_{PHZ}		$R_L = 1 k\Omega$	2.0	50	_	30	125	ns
				4.5] [_	14	25	
				6.0		_	13	21	
Input capacitance	C _{IN}		_			_	3		pF
Output capacitance	C _{OUT}					_	4		pF
Power dissipation capacitance	C _{PD}	(Note 1)	_			_	11		pF

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{|N} + I_{CC}/8 \text{ (per latch)}$



12.8. AC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C, Input: t_f = t_f = 6 ns)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Output transition time	t _{TLH} ,t _{THL}		_	2.0	50	_	75	ns
				4.5		_	15	
				6.0		_	13	
Propagation delay time	t _{PLH} ,t _{PHL}		_	2.0	50	_	155	ns
(LE-Q)				4.5		_	31	
				6.0		_	26	
				2.0	150	_	220	ns
				4.5		_	44	
				6.0		_	37	
Propagation delay time	t _{PLH} ,t _{PHL}		_	2.0	50	_	155	ns
(D-Q)				4.5		_	31	
				6.0		_	26	
				2.0	150	_	220	ns
				4.5		_	44	
				6.0		_	37	
Output enable time	t _{PZL} ,t _{PZH}		$R_L = 1 k\Omega$	2.0	50	_	155	ns
				4.5		_	31	
				6.0		_	26	
				2.0	150	_	220	ns
				4.5	1	_	44	
				6.0		_	37	
Output disable time	t _{PLZ} ,t _{PHZ}		$R_L = 1 k\Omega$	2.0	50	_	155	ns
				4.5		_	31	
				6.0		_	26	



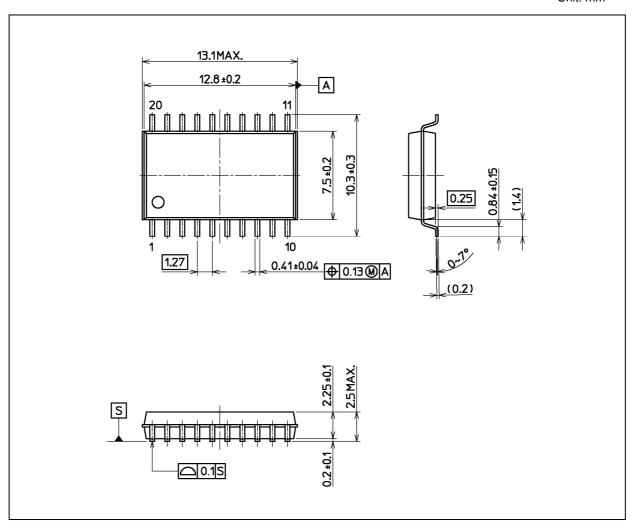
12.9. AC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C, Input: t_r = t_f = 6 ns)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Output transition time	t _{TLH} ,t _{THL}		_	2.0	50	_	90	ns
				4.5		_	18	
				6.0		_	15	
Propagation delay time	t _{PLH} ,t _{PHL}		_	2.0	50	_	190	ns
(LE-Q)				4.5		_	38	
				6.0		_	32	
				2.0	150	_	265	ns
				4.5		_	53	
				6.0		_	45	
Propagation delay time	t _{PLH} ,t _{PHL}		_	2.0	50	_	265	ns
(D-Q)				4.5		_	53	
				6.0		_	45	
				2.0	150	_	265	ns
				4.5		_	53	
				6.0		_	45	
Output enable time	t _{PZL} ,t _{PZH}		$R_L = 1 k\Omega$	2.0	50	_	225	ns
				4.5		_	45	
				6.0		_	38	
				2.0	150	_	265	ns
				4.5	1	_	53	
				6.0		_	45	
Output disable time	t _{PLZ} ,t _{PHZ}		$R_L = 1 k\Omega$	2.0	50	_	225	ns
				4.5		_	45	
				6.0		_	38	



Package Dimensions

Unit: mm



Weight: 0.51 g (typ.)

	Package Name(s)
Nickname: SOIC20	



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